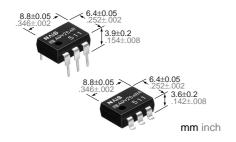




HE (High-function Economy) Type [1-Channel (Form A) Type] —With LED Display—

PhotoMOS RELAYS



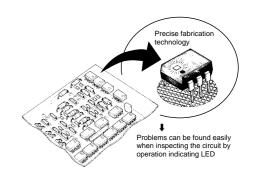
• Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable

closed-circuit offset voltage to enable control of low level voltage signals or analog signals without distortion.

High sensitivity and low on resistance

A stable relay that has a low on resistance of 16 Ω , no metal contacts, and the ability to control a maximum load current of 0.25 A with an input current of 5 mA.

• Low-level off state leakage current In contrast to the SSR with its off state leakage current of several milliamps, the PhotoMOS relay features a very small off state leakage current of only 100 pA even at a high load voltage of 400 V.



FEATURES

- Low on resistance and LED display
- Same compact size of our conventional relays without LED display (W) 6.4×(D) 8.8×(H) 3.9 mm (W) 0.252×(D) 0.346×(H) 0.154 inch.

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Game machines

- High-speed inspection machines
- Industrial equipment

TYPES

Туре	Output rating*			Par	Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load voltage	Load current			Tape and reel packing style		Tube	Tape and reel
			Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC type	400 V	150 mA	AQV254R	AQV254RA	AQV254RAX	AQV254RAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

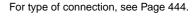
Item		Symbol	Type of connection	AQV254R(A)	Remarks	
Input	LED forward current	lF		25 mA		
	LED reverse voltage	VR		3 V		
	Peak forward current	IFP		60 mA	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		90 mW		
Output	Load voltage (peak AC)	VL		400 V		
		lı	Α	0.15 A		
	Continuous load current		В	0.18 A	A connection: Peak AC, DC B. C connection: DC	
			С	0.25 A	B, O connection. BO	
	Peak load current	Ipeak		0.5 A	A connection: 100 ms (1 shot), V _L = DC	
	Power dissipation	Pout		360 mW		
Total power dissipation		Р⊤		410 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr		-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	Tstg		-40°C to +100°C -40°F to +212°F		

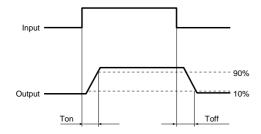
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Symbol	Type of connection	AQV254R(A)	Remarks
	LED operate current		Typical	Fon	_	1.0 mA	IL = Max.
Input			Maximum			3.0 mA	IL = IVIAX.
	I I FD turn off current ⊢		Minimum	Foff	_	0.4 mA	IL = Max.
			Typical			0.9 mA	
	LLED dropout voltage		Typical	VF	_	2.8 V	I _F = 5 mA
			Maximum			3.5 V	
Output	On resistance Maximum Typic Maximum Typic		Typical	Ron	А	12.4 Ω	I _F = 5 mA
			Maximum			16 Ω	I∟ = Max. Within 1 s on time
			Typical	Ron	В	6.2 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
			Maximum			8 Ω	
			Typical	Ron	С	3.1 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
			Maximum			4 Ω	
	Off state leakage current		Maximum	I _{Leak}	_	1 μΑ	I _F = 0 V _L = Max.
Transfer characteristics	Switching speed	Turn on time*	Typical	Ton	_	0.8 ms	I _F = 5 mA
			Maximum			2 ms	I∟ = Max.
		Turn off time*	Typical	Toff	_	0.05 ms	I _F = 5 mA
			Maximum			0.2 ms	I∟ = Max.
	□/() capacitance ⊢		Typical	Ciso	_	1.3 pF	f = 1 MHz
			Maximum			3 pF	V _B = 0
	Initial I/O isolation resistance		Minimum	Riso	_	1,000 ΜΩ	500 V DC

Note: Recommendable LED forward current I_F= 5 mA.

*Turn on/Turn off time





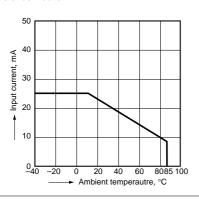
- **■** For Dimensions, see Page 440.
- For Schematic and Wiring Diagrams, see Page 444.
- For Cautions for Use, see Page 449.

REFERENCE DATA

1. Input current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F;

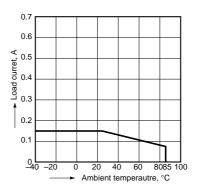
Type of connection: A



2. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F;

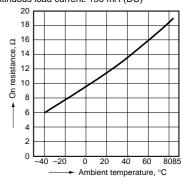
Type of connection: A



3. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: 400 V (DC);

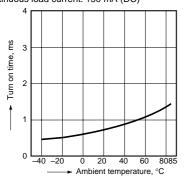
Continuous load current: 150 mA (DC)



AQV254R

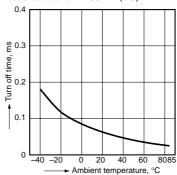
4. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 150 mA (DC)



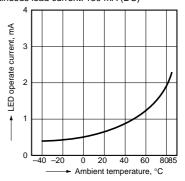
5. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 150 mA (DC)



6. LED operate vs. ambient temperature characteristics

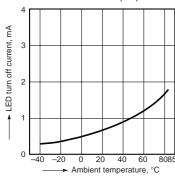
Load voltage: 400 V (DC); Continuous load current: 150 mA (DC)



7. LED turn off current vs. ambient temperature characteristics

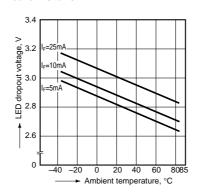
Load voltage: 400 V (DC);

Continuous load current: 150 mA (DC)



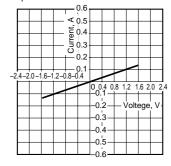
8. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 25 mA

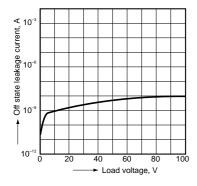


9. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



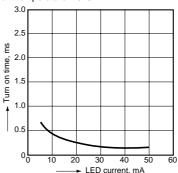
10. Off state leakage current Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



11. LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC);

Continuous load current: 150 mA (DC); Ambient temperature: 25°C 77°F

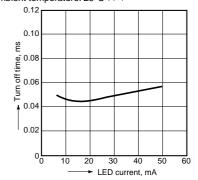


12. LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;

Load voltage: 400 V (DC);

Continuous load current: 150 mA (DC); Ambient temperature: 25°C 77°F



13. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

